

Design of a Low Voltage Class AB Variable Gain Amplifier (VGA)

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Abstract— A variable gain amplifier (VGA) is one of the most significant component in many applications such as analog to digital converter (ADC). In communication receiver, VGA is typically employed in a feedback loop to realize an automatic gain control (AGC), to provide constant signal power to baseband analog-to-digital converter (ADC) for unpredictable received signal strengths. Gain range, power consumption and bandwidth of ADC are strongly influenced by the performance of operational amplifier. VGA is the key element for amplifying process in ADC. However, current class AB VGA is experiencing the limit of bandwidth, which is not suitable for high speed automatic gain control AGC. In order to overcome these limitations a high linearity and wide bandwidth of VGA is indispensable. The aim of this research is to get higher gain and larger bandwidth for VGA. In this research, a low cost, low power voltage and wide bandwidth class AB VGA is designed to mitigate this constraint. Superiority of the proposed VGA has been confirmed by circuit simulation using CEDEC 0.18- μm CMOS process with the help of tools from Mentor Graphics in designing a 100-MHz VGA under 1V supply voltage draining total static power consumption less than 125 μW . The results show that the circuit is able to work with high linearity and wide bandwidth by varying R_f and R_s . Therefore, the frequency response (Gain) and the wide bandwidth of this class AB VGA is better than previously reported class AB VGA. Consequently, this modified class AB VGA is appropriate for high speed applications.

Index Terms—VGA, ADC, CEDEC, CMOS

I. INTRODUCTION

VGA is one of the most essential building blocks for low voltage applications such as wireless communication and mobile imaging applications low voltage applications such as wireless communication and mobile imaging applications [1-3]. Variable gain amplifier (VGA) is signal-conditioning amplifiers with electronically settable voltage gain. There are analog VGAs and digital VGAs, or DVGAs. An analog voltage controls the gain in both, which differ in how it is applied. VGAs are available from dc to gigahertz frequencies and in a variety of I/O configurations. Variable gain amplifiers (VGAs) have been used in a variety of remote sensing and communications equipment for more than a half-century. Applications ranging from ultrasound, radar, lidar to wireless communications and even speech analysis have

utilized variable gain in an attempt to enhance dynamic performance. In communication, receiver, VGA is typically employed in a feedback loop to realize an automatic gain control (AGC), to provide constant signal power to baseband analog-to-digital converter (ADC) for unpredictable received signal strengths. At present, a key design aspect for VGA is the low power dissipation, wide bandwidth and low cost [4]. Indeed, class AB has become very significant alternative for any application requiring VGA over the last few years [5-6].

VGA, as well as other circuits, are required to operate with low power supply voltage and low power consumption. As the process technologies develop, the maximum allowable supply voltage will scale down. It is inevitable that most low power integrated circuits will have to operate with power supply voltages between 1 V to 1.5 V. It is very challenging to design a VGA with high linearity and wide bandwidth with low supply voltage and low power consumption. In addition, VGA is generally required to maintain high linearity and low noise over the entire bandwidth and gain range. It is also important that the bandwidth of the amplifier remains constant when the voltage gain is varied and this can be obtained by employing current-mode techniques [7].

At present, current mode-technique has been extensively implemented in designing a VGA. A circuit using the current-mode technique has many advantages, such as, larger dynamic range, higher bandwidth, greater linearity, simpler circuitry and lower power consumption. In class-AB operation, each device operates the same way as in class B over half the waveform, but also conducts a small amount on the other half. As a result, the region where both devices simultaneously are nearly off is reduced. The result is that when the waveforms from the two devices are combined, the crossover is greatly minimized or eliminated altogether. The exact choice of quiescent current, the standing current through both devices when there is no signal, makes a large difference to the level of distortion and to the risk of thermal runaway that may damage the devices. Often the bias voltage applied to set this quiescent current has to be adjusted with the temperature of the output transistors [8].

Since its operation is limited at class-A amplifier, signal swing is small compared to class-AB amplifier [9]. This paper presents an improved VGA to the circuit designed by P. Khumsat et. al [10]. It will be shown that the proposed circuit

operates in class-AB manner outperforms its predecessor (class-A), especially, in terms of signal swing and linearity while maintaining the same static power consumption and silicon area [11]. So in VGA, class AB amplifier is widely used.

A number of class AB VGA have been designed so far to achieve high linearity and wide bandwidth with acceptable power dissipation. However, researchers experienced gain limitation issues in wide bandwidth and the transistor's size as well. P. Khumsat et. al implemented a low cost, low power and highly reliable class AB VGA in Spectre 0.18 μ m CMOS process [10]. The research showed that in designing a 50MHz VGA under 1V power supply, the highest frequency response (gain) is 25dB. However, it suffers from instability at high frequencies as mentioned before.

In this research, a low voltage class AB VGA for ADC is designed to attain the VGA with high dynamic range, high linearity and wide bandwidth with low power supply and low power consumption. This design overcomes the limitations of the conventional class AB VGA. Current mode technique has been used in this design to achieve better circuit performance. Small size of transistor is used in this design to reduce the size of circuit and cost as well. The proposed class AB VGA amplifier is designed in CEDEC 0.18 μ m process. Simulations results show that the modified low voltage class AB VGA performs better than the sense amplifier designed by P. Khumsat et. al.

II. CLASS AB OUTPUT STAGES

The amplifier output stage is an important part of an operational amplifier, as it is the stage that delivers the input signal to the load. In a well-designed two or three-stage operational amplifier it is also the stage which consumes most of the amplifier biasing current and ultimately sets limits on linearity of the amplifier and its maximum tolerated capacitive load. When the operating environment of an amplifier requires it to drive low ohmic resistive loads, high current source loads or large capacitive loads, the output stage must be able to source and sink currents that greatly exceed its biasing current. In practise this requires some kind of common drain-based class AB output stage, as shown conceptually in Fig. 1, at least in a low voltage environment, in order not to degrade the available dynamic range any further.

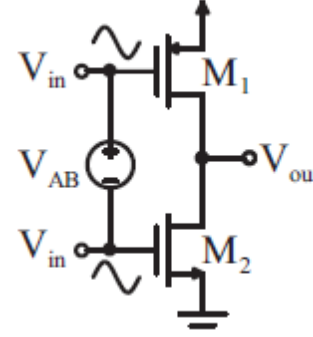


Fig. 1. A conceptual common drain stage-based class AB output stage.

III. TWO STAGE CURRENT MODE VARIABLE GAIN AMPLIFIER

The previously proposed VGA in [10] has shown its versatility and potential to operate at low supply voltage, low power consumption with high bandwidth while maintaining good degree of dynamic range and occupying small silicon area. This VGA's architecture is presented in Fig. 2, which is a cascade of a linear transconductance cascaded and a linear transimpedance amplifier with shunt-feedback resistors (R_f).

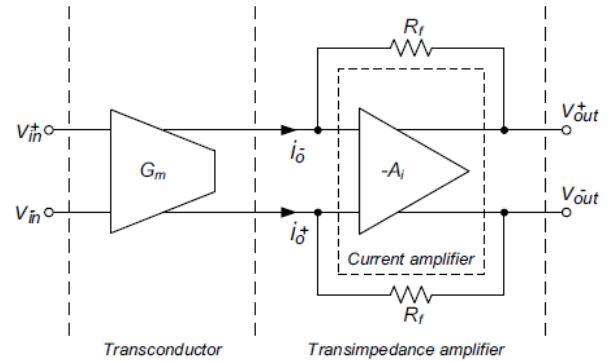


Fig. 2: Architecture of the proposed VGA stage in [10].

This allows constant bandwidth when varying the voltage gain. The voltage gain of the VGA circuit is the product of the transconductance gain (G_m) and the transimpedance gain (R_m). The transimpedance gain is given by

$$R_m = -\frac{(R_f A_i - R_{in})}{1 + A_i} \quad (1)$$

where R_{in} and A_i , respectively, are the input resistance and the current gain of the current amplifier. Note that, when $A_i \gg 1$, we have $R_m \approx -R_f$. There, a linear G_m and a high-gain current amplifier are required to realize a high-linearity VGA. The

proposed VGA circuit realization in CMOS is also depicted in Fig. 3. The circuit is very compact; however it has a bandwidth limitation at which the bandwidth is restricted to 50MHz and using the big size of transistor. Table 1 shows parameter or size of transistor that have been used in previous circuit.

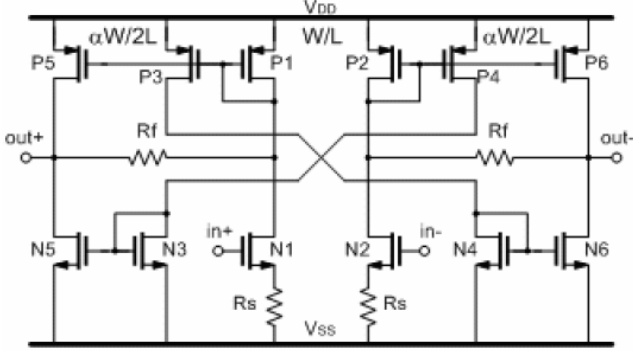


Fig. 3: Circuit realization of the proposed circuit [10] with CMOS

Table 1: Previous circuit's [10] transistor size of VGA operating under a 1 V supply power.

Transistor	W/L (um/um)
N1-N2	1.5/0.18
P1-P2	10/0.5
P3-P6	25/0.5
N3-N6	5/0.5

IV. PROPOSED CLASS AB VARIABLE GAIN AMPLIFIER

Fig. 4 shows the circuit implementation of the proposed VGA cell, which combines a source degeneration differential input transconductance amplifier (N1 – N2, R_s) and a current-mode transimpedance amplifier (P1 – P6, N3 – N6) in order to maximum transconductance/bias current efficiency and minimize supply voltage and noise [13-14]. Cascaded current mirrors are used to implement the DC current sources. Despite these advantages, such structure possesses a serious drawback in being unable to reject common-mode signal. The second stage mirror-based current amplifier (P1 – P6, N3 – N6) resolves this problem by employing feed forward technique that allows differential signals to be constructively combined while on the other hand cancel a common-mode signal [15-16]. This current amplifier combined with feedback resistors R_s form a transimpedance amplifier necessary for current-to-voltage conversion. Moreover, such output stage also provides a class-AB operation allowing larger signal swing compared to its predecessor presented in [17-18]. Thus the major advantage of such VGA circuit is its ability to offer excellent signal linearity without sacrificing the original advantages on both aspects of the power consumption and circuit complexity.

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Fig. 4: Improved VGA based on the structure in Fig. 1a with class-AB output stage and signal feed forward topology.

It is important to note that the size of each transistor is reduced according to the ratio (W/L) to get a smaller size of IC. Besides that, the number of resistor R_s that have been used in previous circuit is also reduce from 2 to 1. Table 2 shows the comparison size of transistor between this work and previous circuit.

Table 2: Comparison of VGA transistors

Transistor	W/L (um/um), Circuit in [10]	W/L (um/um), This work
N1-N2	1.5/0.18	1.5/0.18
P1-P2	10/0.5	3.6/0.18
P3-P6	25/0.5	9/0.18
N3-N6	5/0.5	1.8/0.18

A small-signal transconductance of the first stage is simply expressed as

$$G_m = \frac{g_m}{1 + g_m R_s + s R_s C_{gs}} \quad (2)$$

where g_m and C_{gs} are respectively transconductance and gate source capacitance of N1 and N2. The amplifier differential current gain A_i and input resistance R_{in} have been analyzed to be

$$A_i = \frac{g_{mx}}{(g_{mi} + s C_x)} \left(1 + \frac{g_{my}}{g_{my} + s C_y} \right) \quad (3)$$

and

$$R_{in} = \frac{1}{g_{mi} + s C_x} \quad (4)$$

where g_{mi} , g_{mx} and g_{my} are transconductance of P1 – P2, P3 – P6 and N3 – N6 respectively. The parameters C_x and C_y are equivalent total capacitance (referred to ground) at gates of P1 (P2) and N3 (N4) whose values are mainly contributed from gate-source capacitance. At low frequency, since $g_{mx} = g_{mi}(\alpha/2)$, thus A_i of Fig. 4 equals to α , which is the same as what obtained from the original circuit in Fig. 3. Thus, by

substituting (3) and (4) into (1), a small-signal transimpedance gain could be obtained to be

$$R_m = - \frac{\alpha [2R_f \frac{1}{g_{mx}} + s \frac{C_y}{g_{my}} (R_f \frac{1}{g_{mx}})]}{2[1 + \alpha + s (\frac{C_y}{g_{my}} (1 + \frac{\alpha}{2}) + \frac{C_x}{g_{mi}}) + s^2 \frac{C_x C_y}{g_{mi} g_{my}}]} \quad (5)$$

The feedback resistor R_f is selected to set a voltage gain range whereas a source degeneration resistor R_s is tuned to vary the amplifier gain. The minimum value of R_s sets the maximum gain for a specific gain range (as previously set by R_f) and it also defines the maximum static current consumed by the VGA. The similar technique proposed in [19] can be used to tune the grounded resistor R_s .

V. RESULT AND DISCUSSION

The improved class AB VGA circuit with a single 1V power supply voltage have been designed and simulated in CEDEC 0.18- μm CMOS process. Simulations were executed to evaluate the circuit performance of the modified class AB VGA with the previously reported class AB VGA [10]. With $\alpha = 5$, transistor sizing of the VGA circuit is listed in Table 3. The minimum value of R_s is chosen to be 500 Ohms to ensure a maximum power consumption not exceeding 120uW for a bandwidth over 100MHz.

Table 3: Transistor sizing within the VGA operating under a 1V supply voltage.

Transistor	W/L (um/um)
N1-N2	1.5/0.18
P1-P2	3.6/0.18
P3-P6	9/0.18
N3-N6	1.8/0.18

By using a transient analysis within Mentor Graphics design architect IC (DA-IC), Fig. 5 depicts the input and output signal swing at the maximum voltage gain of 26dB where we can see that the output signal is amplified.

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Fig. 5: Simulation result of output swing at maximum voltage gain of 26 dB for 1V power supply.

Fig. 6 shows four families of curves of measured gain response, which was obtained by setting the feedback resistors (R_f) from 15k to 500k. This renders coarse gain tuning of the amplifier, where high gain settings (upper family of curves) and low gain settings (lower family of curves) can be achieved with $R_f = 500\text{k}$, and $R_f = 15\text{k}$, respectively. Within each family

of curve, the value of R_s was changed to obtain fine gain tuning. It can be seen that voltage gain control with constant bandwidth can be achieved by varying R_s , while changing R_f affects the bandwidth of the VGA because R_f determines the dominant output pole frequency of the circuit. Therefore to design the VGA, R_f should be chosen first according to the bandwidth requirement and R_s is then tuned to adjust the voltage gain.

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Fig. 6: Frequency response of the VGA where R_f : 500k Ω , 150k Ω , 50k Ω , 15k Ω and R_s : 500 Ω , 5k Ω , 15k Ω .

A comparisons study of class AB VGA between this work and P. Khumsat et. al is shown in Table 4. From the study, it is shown that the circuit is able to vary the voltage gain in linear dB manner from -7 to 26 dB. The total power consumption is less than 125uW from a single 1 V power supply voltage and has a wide and constant bandwidth, which is better than the P. Khumsat et. al. Table 4 also summarizes the experimental performance of the overall class AB VGA. It can see that the proposed class AB VGA can achieved the similar gain range to other reported VGA, while operating under lower supply voltage and smaller size transistor indicating that the proposed VGA is more superior.

Table 4: VGA performance comparison

Parameters	This work	Circuit in [10]
Technology	CEDEC 0.18um CMOS	Spectre 0.18um CMOS
Bandwidth	~100Mhz	~50Mhz
Gain range at constant bandwidth	26dB	25dB

The modified class AB variable gain amplifier (VGA) circuit layout is designed in CEDEC 0.18- μm CMOS process. In Fig. 7, the completed chip layout of the modified class AB VGA is presented. In this layout, the resistors are excluded from the IC layout and being replaced with an external resistor component because to draw a resistor layout with high resistance value in your IC chip layout is not that practical as the resistor layout drawn will be very big which will cause a large die size and high cost for chip to tape out. In this research, the size for each cell of the MOS transistors in class AB VGA circuit is smaller, which proves that the modified class AB VGA circuit size is smaller than the circuit size designed by P. Khumsat et. al.

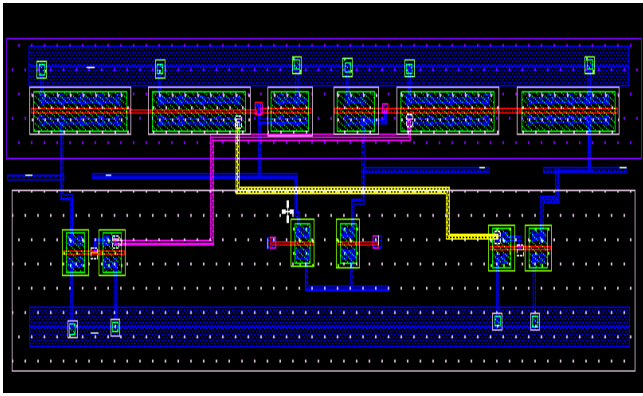


Fig. 7: A layout design of class AB variable gain amplifier

VI. CONCLUSION

An improved design and a comparative study of class-AB variable gain amplifier using two stage architecture comprising a linear transconductor cascaded by a current amplifier-based feedback transimpedance amplifier is presented in this research. The modified circuit has been designed by using the CEDEC 0.18- μm CMOS. In this research, small design parameters were used to reduce the cost and die size of whole chip. According to the research results, it has been proven that, the circuit is capable to achieve high linearity and wide bandwidth. The results also verify that by using current mode technique, the voltage gain of the VGA can be tuned while the bandwidth remains constant. Additionally, the circuit size reduced significantly by using small transistors and less number of resistor.

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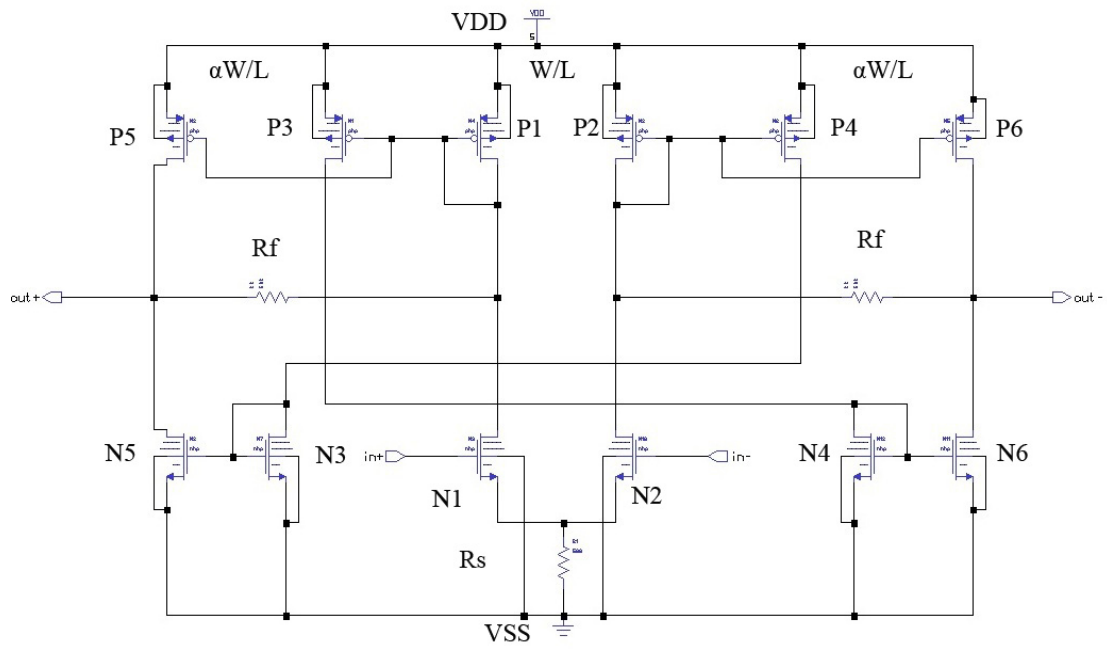


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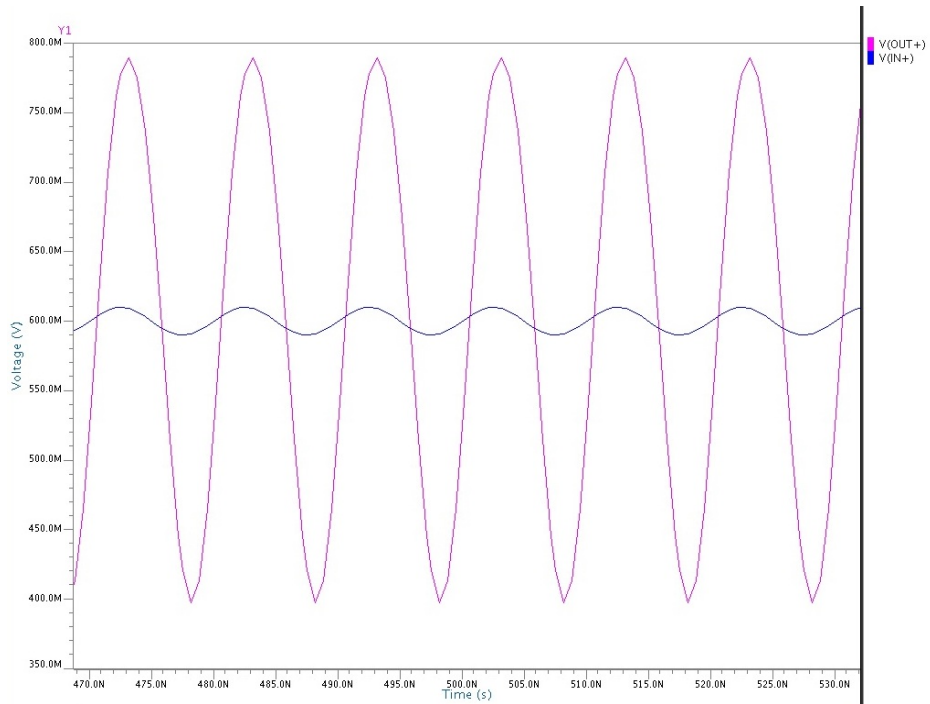


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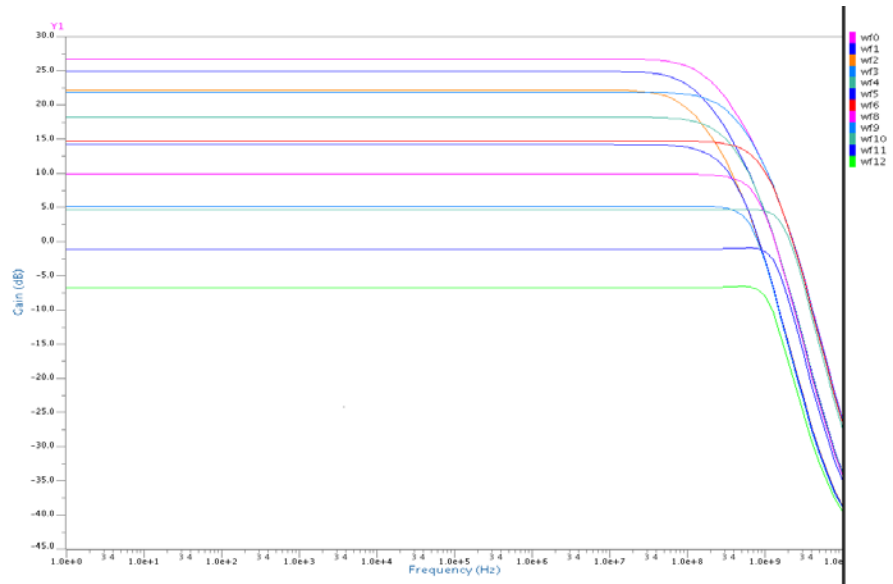


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